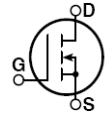

 Common
 Source


RF POWER MOSFETs

N-CHANNEL ENHANCEMENT MODE

300V 150W 60MHz

The ARF465A and 465B comprise a symmetric pair of common source RF power transistors designed for push-pull scientific, commercial, medical and industrial RF power amplifier applications up to 60 MHz.

• **Specified 300 Volt, 40.68 MHz Characteristics:**

Output Power = 150 Watts.

Gain = 13dB (Class C)

Efficiency = 75%

• **Low Cost Common Source RF Package.**

• **Low V_{th} thermal coefficient.**

• **Low Thermal Resistance.**

• **Optimized SOA for Superior Ruggedness.**


MAXIMUM RATINGS

 All Ratings: $T_C = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	ARF465A/B(G)	UNIT
V_{DSS}	Drain-Source Voltage	1200	Volts
V_{DGO}	Drain-Gate Voltage	1200	
I_D	Continuous Drain Current @ $T_C = 25^\circ\text{C}$	6	Amps
V_{GS}	Gate-Source Voltage	± 30	Volts
P_D	Total Power Dissipation @ $T_C = 25^\circ\text{C}$	250	Watts
$R_{\theta JC}$	Junction to Case	0.50	$^\circ\text{C/W}$
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to 150	$^\circ\text{C}$
T_L	Lead Temperature: 0.063" from Case for 10 Sec.	300	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage ($V_{GS} = 0V, I_D = 250 \mu\text{A}$)	1200			Volts
$V_{DS(ON)}$	On State Drain Voltage ^① ($I_D(ON) = 3A, V_{GS} = 10V$)			8	
I_{DSS}	Zero Gate Voltage Drain Current ($V_{DS} = V_{DSS}, V_{GS} = 0V$)			25	μA
	Zero Gate Voltage Drain Current ($V_{DS} = 0.8 V_{DSS}, V_{GS} = 0V, T_C = 125^\circ\text{C}$)			250	
I_{GSS}	Gate-Source Leakage Current ($V_{GS} = \pm 30V, V_{DS} = 0V$)			± 100	nA
g_{fs}	Forward Transconductance ($V_{DS} = 25V, I_D = 3A$)	3	4		mhos
$V_{GS(TH)}$	Gate Threshold Voltage ($V_{DS} = V_{GS}, I_D = 50\text{mA}$)	3		5	Volts

 **CAUTION:** These Devices are Sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

DYNAMIC CHARACTERISTICS

ARF465A/B(G)

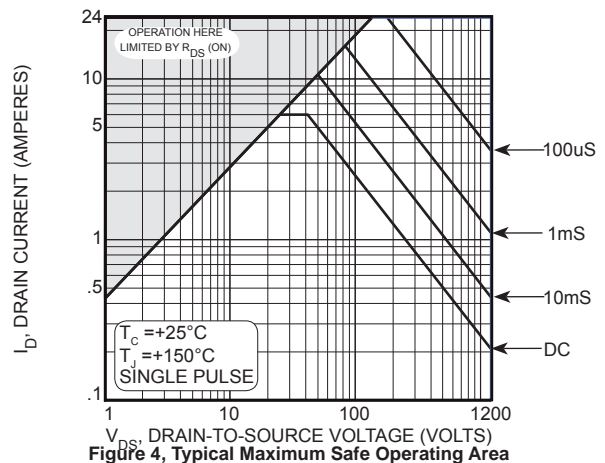
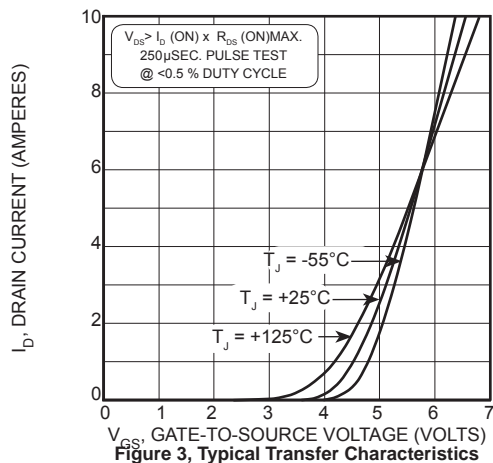
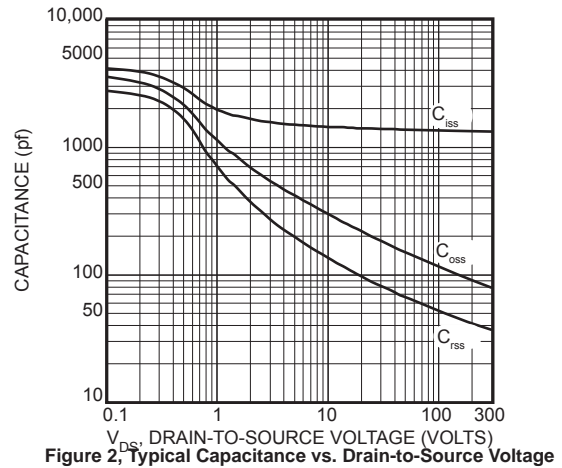
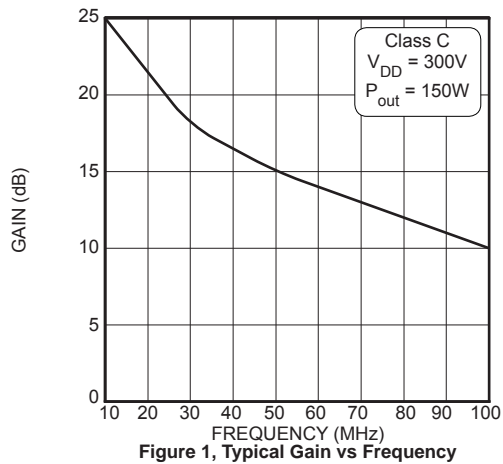
Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
C_{iss}	Input Capacitance	$V_{GS} = 0V$ $V_{DS} = 200V$ $f = 1\text{ MHz}$		1200	1500	pF
C_{oss}	Output Capacitance			80	100	
C_{rss}	Reverse Transfer Capacitance			30	50	
$t_{d(on)}$	Turn-on Delay Time	$V_{GS} = 15V$ $V_{DD} = 0.5V$ $I_D = I_{D[Cont.]} @ 25^\circ C$ $R_G = 1.6W$		7	15	ns
t_r	Rise Time			5	10	
$t_{d(off)}$	Turn-off Delay Time			21	34	
t_f	Fall Time			12	25	

FUNCTIONAL CHARACTERISTICS

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
G_{PS}	Common Source Amplifier Power Gain	$f = 40.68\text{ MHz}$	13	15		dB
η	Drain Efficiency	$V_{GS} = 0V$ $V_{DD} = 300V$	70	75		%
Ψ	Electrical Ruggedness VSWR 6:1	$P_{out} = 150W$	No Degradation in Output Power			

① Pulse Test: Pulse width < 380 μ S, Duty Cycle < 2%

Microsemi Reserves the right to change, without notice, the specifications and information contained herein.



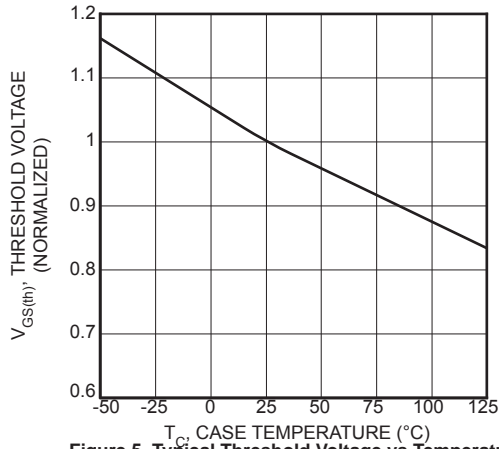


Figure 5, Typical Threshold Voltage vs Temperature

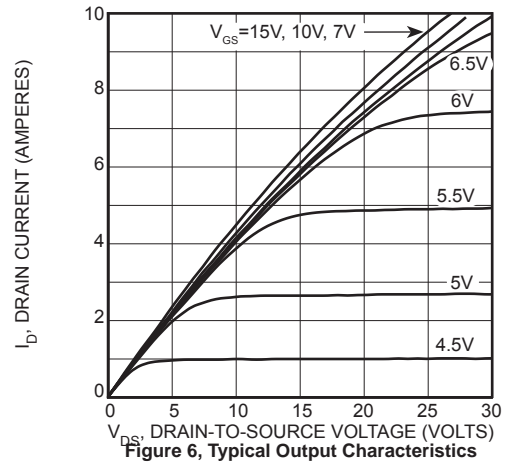


Figure 6, Typical Output Characteristics

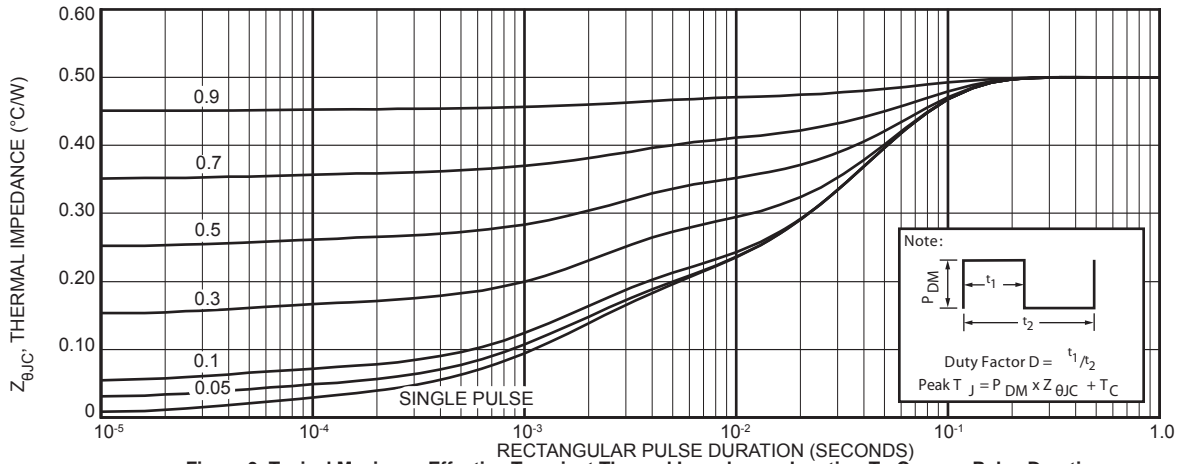


Figure 9, Typical Maximum Effective Transient Thermal Impedance, Junction-To-Case vs Pulse Duration

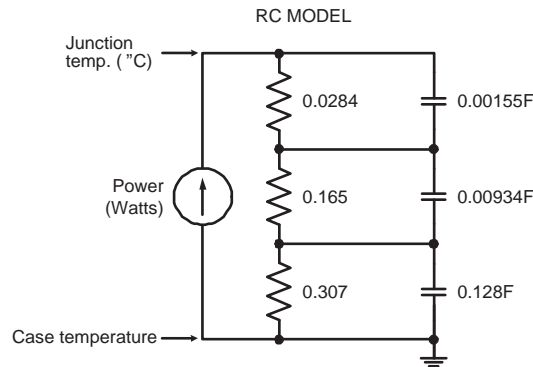


Figure 9a, TRANSIENT THERMAL IMPEDANCE MODEL

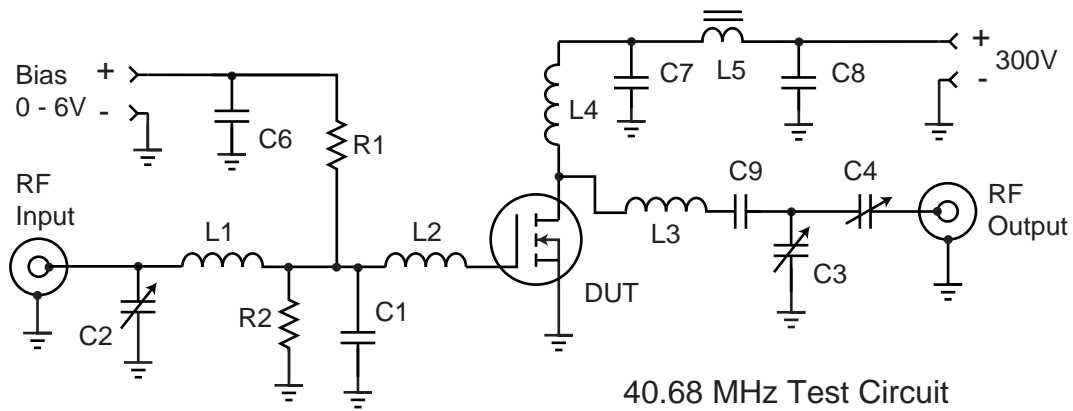
Table 1 - Typical Class AB Large Signal input - Output Impedance

Freq. (MHz)	Z _{in} (Ω)	Z _{OL} (Ω)
2.0	21.4 - j 8.7	206 - j 45
13.5	2.6 - j 7.3	68 - j 99
27	.54 - j 2.9	22 - j 64
40	.22 - j .69	10.5 - j 44
65	.31 + j 1.65	4.4 - j 27

Z_{in} - Gate shunted with 25Ω

I_{DQ} = 100mA

Z_{OL} - Conjugate of optimum load for 150 Watts output at V_{dd} = 300V

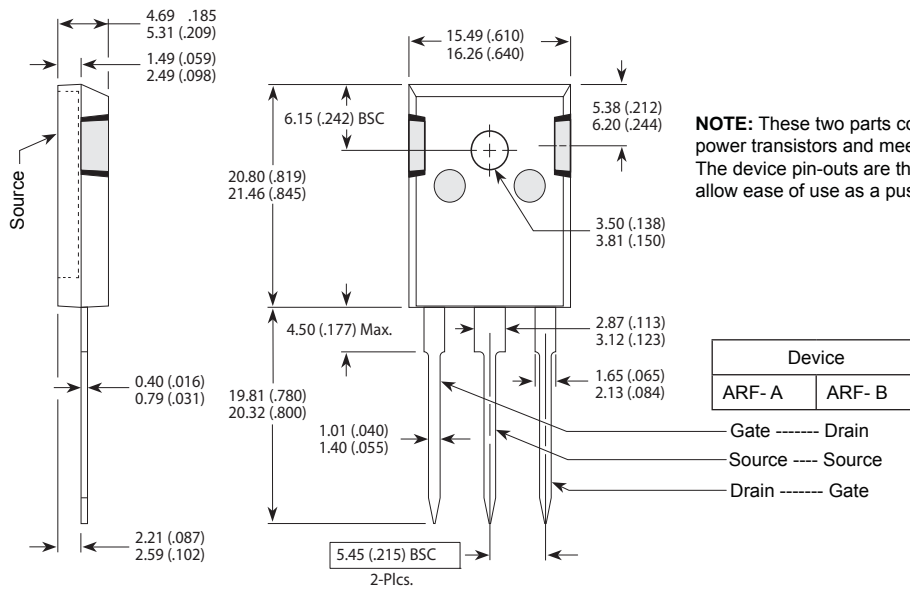


40.68 MHz Test Circuit

- C1 - 1000pF 100V chip ATC 700B
- C2-C5 - Arco 463 Mica trimmer
- C6-C8 - .01 μ F 500V ceramic chip
- C9 - 2200 pF COG 500 V chip
- L1 - 4t #20 AWG .25"ID .3"L ~110 nH
- L2 - 2t #20 AWG .25"ID .3"L ~ 25 nH

- L3-- 4t #16 AWG .4" ID .5"L ~290 nH
- L4 -- 25t #24 AWG .35"ID ~2uH
- L5-- VK200-4B ferrite choke 3uH
- R1-R2 -- 51 Ohm 0.5W Carbon
- DUT = ARF465A/B

TO-247 Package Outline



Dimensions in Millimeters and (Inches)

HAZARDOUS MATERIAL WARNING:

The ceramic portion of the device between leads and mounting flange is beryllium oxide. Beryllium oxide dust is highly toxic when inhaled. Care must be taken during handling and mounting to avoid damage to this area. These devices must never be thrown away with general industrial or domestic waste.

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- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
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- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
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